

PATENT APPLICATION
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q79703

Hisayuki MIKI, et al.

Allowed: May 19, 2009

Appln. No.: 10/586,849

Group Art Unit: 2814

Confirmation No.: 3462

Examiner: Wai Sing LOUIE

Filed: July 20, 2006

For: GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR MULTILAYER
STRUCTURE AND PRODUCTION METHOD THEREOF

AMENDMENT UNDER 37 C.F.R. §1.312

MAIL STOP ISSUE FEE

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

Pursuant to the provisions of 37 C.F.R. §1.312, please amend the above-identified
application as follows on the accompanying pages.

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